



BSS84W

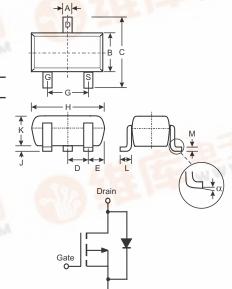
P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 and 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Code (See Page 2): K84
- Ordering & Date Code Information: See Page 2
- Weight: 0.006 grams (approximate)



	SOT-323									
Dim	Min	Max								
Α	0.25	0.40								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 N	ominal								
E	0.30	0.40								
G	1.20	1.40								
Н	1.80	2.20								
J	0.0	0.10								
K	0.90	1.00								
L	0.25	0.40								
M	0.10	0.18								
α	0°	8°								
All Din	ensions	in mm								

Maximum Ratings @ $T_A = 25$ °C unless otherwise specified

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	-50	V	
Drain-Gate Voltage (Note 1)	17.10	V _{DGR}	-50	V	
Gate-Source Voltage Con	ntinuous	V _{GSS}	±20	V	
Drain Current (Note 1) Con	ntinuous	I _D	-130	mA	
Total Power Dissipation (Note 1)		P _d	200	mW	
Thermal Resistance, Junction to Ambient		$R_{ heta JA}$	625	°C/W	
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C	

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02004

- 2. No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.
- 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.





Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)			•	•	•	
Drain-Source Breakdown Voltage	BV _{DSS}	-50	-75	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_		-15 -60 -100	μΑ μΑ nA	$\begin{array}{l} V_{DS} = \text{-}50\text{V}, V_{GS} = 0\text{V}, T_{J} = 25^{\circ}\text{C} \\ V_{DS} = \text{-}50\text{V}, V_{GS} = 0\text{V}, T_{J} = 125^{\circ}\text{C} \\ V_{DS} = \text{-}25\text{V}, V_{GS} = 0\text{V}, T_{J} = 25^{\circ}\text{C} \end{array}$
Gate-Body Leakage	I _{GSS}	_	_	±10	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V _{GS(th)}	-0.8	-1.6	-2.0	V	$V_{DS} = V_{GS}$, $I_D = -1mA$
Static Drain-Source On-Resistance	R _{DS (ON)}	_	6	10	Ω	$V_{GS} = -5V, I_D = -0.100A$
Forward Transconductance	g _{FS}	.05	_	_	S	$V_{DS} = -25V, I_D = -0.1A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	C _{iss}	_	_	45	pF	
Output Capacitance	Coss	_	_	25	pF	$V_{DS} = -25V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	_	12	pF	
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{D(ON)}	_	10	_	ns	$V_{DD} = -30V$, $I_D = -0.27A$,
Turn-Off Delay Time	t _{D(OFF)}	_	18	_	ns	$R_{GEN} = 50\Omega$, $V_{GS} = -10V$

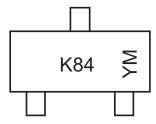
Ordering Information (Notes 4 and 6)

Device	Packaging	Shipping
BSS84W-7-F	SOT-323	3000/Tape & Reel

Notes: 4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

- 5. Short duration test pulse used to minimize self-heating effect.
- 6. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

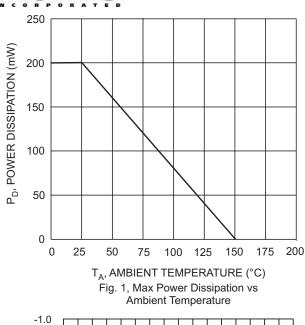


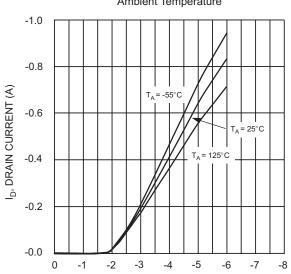
K84= Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

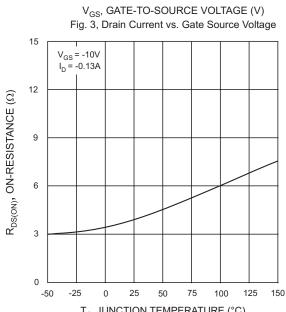
Date Code Key

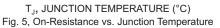
Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009
Code	J	K	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

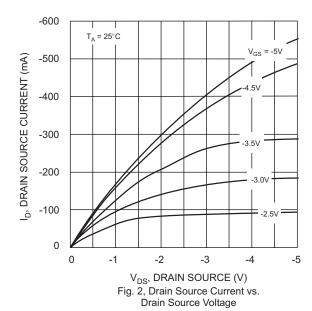












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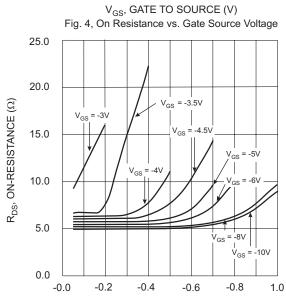
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 $\label{eq:ldots} {\rm I_D,\,DRAIN\,CURRENT\,(A)}$ Fig. 6, On-Resistance vs. Drain Current



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